**Preferred Device** 

## Product Preview

# Common Anode Silicon Dual Switching Diodes

These Common Anode Silicon Epitaxial Planar Dual Diodes are designed for use in ultra high speed switching applications. The DAP222 device is housed in the SOT–723 package which is designed for low power surface mount applications, where board space is at a premium.

- Fast t<sub>rr</sub>
- Low C<sub>D</sub>
- ESD Performance: Human Body Model; > 2000 V, Machine Model > 200 V
- Available in 4 mm Tape and Reel
- This is a Pb-Free Device

### **MAXIMUM RATINGS** $(T_A = 25^{\circ}C)$

Rating	Symbol	Value	Unit	
Reverse Voltage	V <sub>R</sub> 80		V	
Peak Reverse Voltage	$V_{RM}$	80	V	
Forward Current	I <sub>F</sub> 100		mA	
Peak Forward Current	I <sub>FM</sub>	300	mA	
Peak Forward Surge Current	I <sub>FSM</sub> (Note 1)	2.0	Α	

### THERMAL CHARACTERISTICS

Rating	Symbol	Max	Unit	
Power Dissipation	$P_{D}$	260	mW	
Junction Temperature	$T_J$	150	°C	
Storage Temperature	T <sub>stg</sub>	-55 ~ <b>+</b> 150	°C	

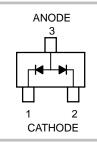
Maximum ratings are those values beyond which device damage can occur. Maximum ratings applied to the device are individual stress limit values (not normal operating conditions) and are not valid simultaneously. If these limits are exceeded, device functional operation is not implied, damage may occur and reliability may be affected.

1.  $t = 1.0 \mu S$ .



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### http://onsemi.com



### MARKING DIAGRAM



SOT-723 CASE 631AA STYLE 4



P9

- = Specific Device Code
- 1 = Date Code

### **ORDERING INFORMATION**

Device	Package	Shipping <sup>†</sup>		
DAP222M3T5G	SOT-723	8000/Tape & Reel		

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification Brochure, BRD8011/D.

**Preferred** devices are recommended choices for future use and best overall value.

This document contains information on a product under development. ON Semiconductor reserves the right to change or discontinue this product without notice.

## **ELECTRICAL CHARACTERISTICS** $(T_A = 25^{\circ}C)$

Characteristic	Symbol	Condition		Max	Unit
Reverse Voltage Leakage Current	$I_R$	V <sub>R</sub> = 70 V		0.1	μΑ
Forward Voltage	V <sub>F</sub>	I <sub>F</sub> = 100 mA	_	1.2	V
Reverse Breakdown Voltage	$V_{R}$	I <sub>R</sub> = 100 μA	80	_	V
Diode Capacitance	$C_D$	$V_R = 6.0 \text{ V}, f = 1.0 \text{ MHz}$	-	3.5	pF
Reverse Recovery Time	Recovery Time $t_{rr}$ $I_F = 5.0$ mA, $V_R = 6.0$ V, $R_L = 100$ $\Omega$ , $I_{rr} = 0.1$ $I_R$ $(Note 2)$		ı	4.0	ns

<sup>2.</sup>  $t_{rr}$  Test Circuit for DAP222 in Figure 4.

### TYPICAL ELECTRICAL CHARACTERISTICS

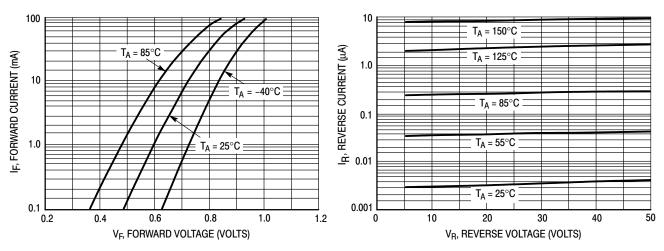


Figure 1. Forward Voltage

Figure 2. Reverse Current

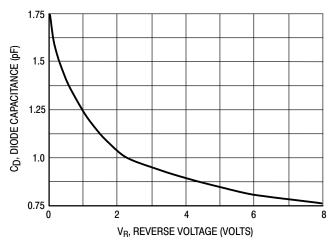


Figure 3. Diode Capacitance

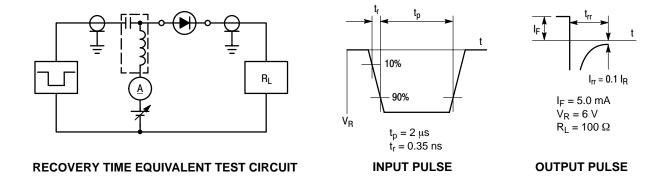
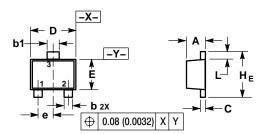


Figure 4. Reverse Recovery Time Test Circuit

#### PACKAGE DIMENSIONS

SOT-723 CASE 631AA-01 **ISSUE B** 



#### NOTES:

- 1. DIMENSIONING AND TOLERANCING PER ANSI
- Y14.5M, 1982.
- CONTROLLING DIMENSION: MILLIMETERS.
- MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH. MINIMUM LEAD THICKNESS IS THE MINIMUM
- THICKNESS OF BASE MATERIAL.
  DIMENSIONS D AND E DO NOT INCLUDE MOLD FLASH, PROTRUSIONS OR GATE BURRS.

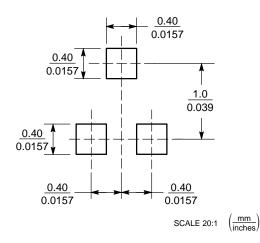
	MILLIMETERS			INCHES		
DIM	MIN	NOM	MAX	MIN	NOM	MAX
Α	0.45	0.50	0.55	0.018	0.020	0.022
b	0.15	0.21	0.27	0.0059	0.0083	0.0106
b1	0.25	0.31	0.37	0.010	0.012	0.015
С	0.07	0.12	0.17	0.0028	0.0047	0.0067
D	1.15	1.20	1.25	0.045	0.047	0.049
E	0.75	0.80	0.85	0.03	0.032	0.034
е	0.40 BSC		0.016 BSC			
ΗE	1.15	1.20	1.25	0.045	0.047	0.049
L	0.15	0.20	0.25	0.0059	0.0079	0.0098

STYLE 4:

PIN 1. CATHODE 2. CATHODE

- 3. ANODE

#### SOLDERING FOOTPRINT\*



\*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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